

General Description

The AOZ1022 is a synchronous high efficiency, simple to use, 3A buck regulator. The AOZ1022 works from a 4.5V to 16V input voltage range, and provides up to 3A of continuous output current with an output voltage adjustable down to 0.8V.

The AOZ1022 comes in a DFN 5x4 and an EPAD SO-8 package and is rated over a -40°C to +85°C ambient temperature range.

Features

- 4.5V to 16V operating input voltage range
- Synchronous rectification: 100mΩ internal high-side switch and 20mΩ Internal low-side switch
- High efficiency: up to 95%
- Internal soft start
- Active high power good state
- Output voltage adjustable to 0.8V
- 3A continuous output current
- Fixed 500kHz PWM operation
- Cycle-by-cycle current limit
- Pre-bias start-up
- Short-circuit protection
- Thermal shutdown
- Small size DFN 5x4 and EPAD SO-8 package

Applications

- Point of load DC-DC conversion
- PCIe graphics cards
- Set top boxes
- DVD drives and HDD
- LCD panels
- Cable modems
- Telecom/networking/datacom equipment



Typical Application

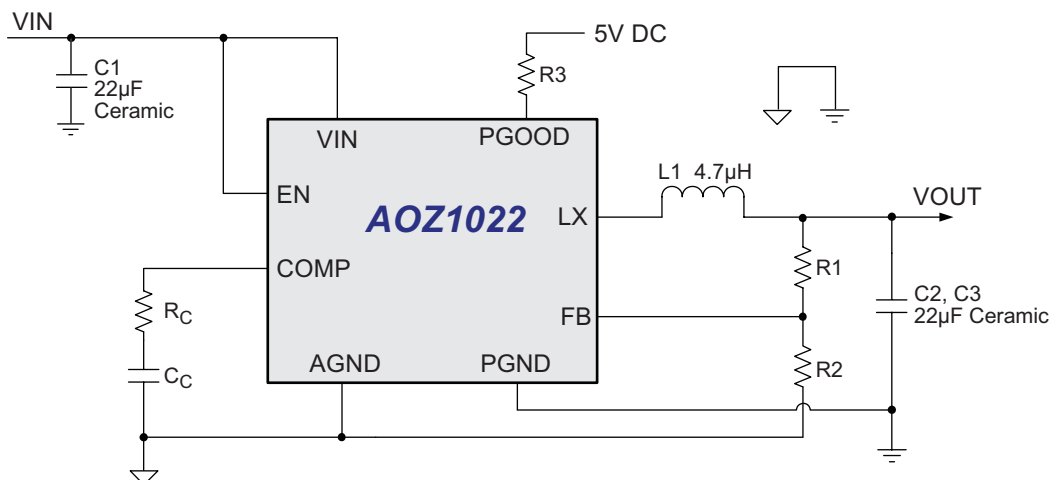


Figure 1. 3.3V/3A Synchronous Buck Regulator

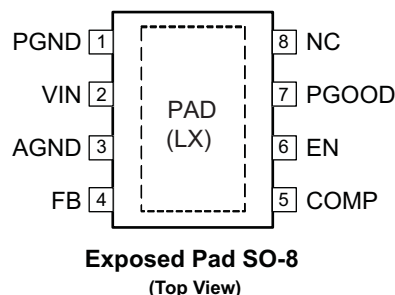
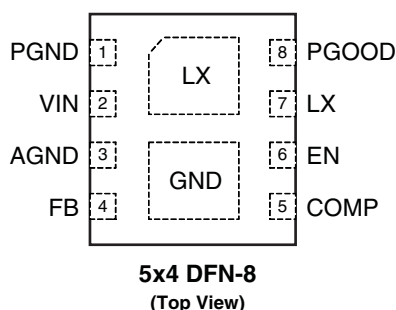
Ordering Information

| Part Number | Ambient Temperature Range | Package | Environmental |
|-------------|---------------------------|-----------|---------------|
| AOZ1022DI | -40°C to +85°C | DFN 5x4 | |
| AOZ1022 | -40°C to +85°C | EPAD S0-8 | Green |



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant.
Please visit www.aosmd.com/web/quality/rohs_compliant.jsp for additional information.

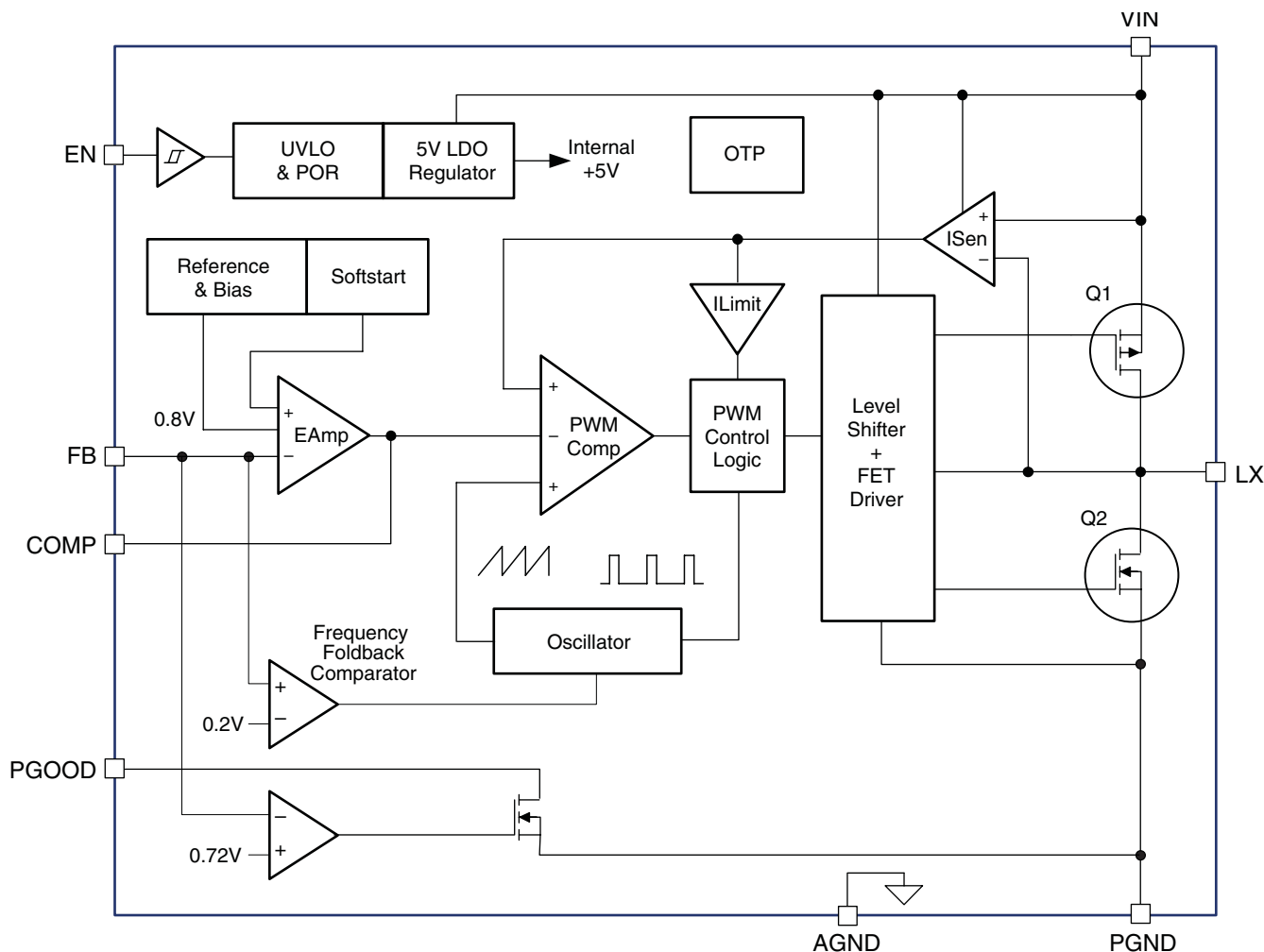
Pin Configuration



Pin Description

| Pin Number | | Pin Name | Pin Function |
|------------|------------------|----------|---|
| 5x4 DFN-8 | Exposed Pad SO-8 | | |
| 1 | 1 | PGND | Power ground. PGND needs to be electrically connected to AGND. |
| 2 | 2 | V_{IN} | Supply voltage input. When V_{IN} rises above the UVLO threshold and EN is logic high, the device starts up. |
| 3 | 3 | AGND | Analog ground. AGND is the reference point for controller section. AGND needs to be electrically connected to PGND. |
| 4 | 4 | FB | Feedback input. The FB pin is used to set the output voltage via a resistor divider between the output and AGND. |
| 5 | 5 | COMP | External loop compensation pin. Connect a RC network between COMP and AGND to compensate the control loop. |
| 6 | 6 | EN | Enable pin. Pull EN to logic high to enable the device. Pull EN to logic low to disable the device. if on/off control is not needed, connect it to V_{IN} and do not leave it open. |
| 7 | Pad | LX | Switching node. LX is the drain of the internal PFET. LX is used as the thermal pad of the power stage. |
| 8 | 7 | PGOOD | Power Good Output. PGOOD is an open-drain output that indicates the status of output voltage. PGOOD is pulled low when output is below 90% of the normal regulation. |
| | 8 | NC | No Connect. Pin 8 is not internally connected. |

Block Diagram



Absolute Maximum Ratings

Exceeding the Absolute Maximum Ratings may damage the device.

| Parameter | Rating |
|--------------------------------|------------------------|
| Supply Voltage (V_{IN}) | 18V |
| LX to AGND | -0.7V to $V_{IN}+0.3V$ |
| EN to AGND | -0.3V to $V_{IN}+0.3V$ |
| FB to AGND | -0.3V to 6V |
| COMP to AGND | -0.3V to 6V |
| PGND to AGND | -0.3V to 0.3V |
| PGOOD to AGND | -0.3V to 6V |
| Junction Temperature (T_J) | +150°C |
| Storage Temperature (T_S) | -65°C to +150°C |
| ESD Rating ⁽¹⁾ | 2.0kV |

Note:

1. Devices are inherently ESD sensitive, handling precautions are required. Human body model rating: 1.5kΩ in series with 100pF.

Recommended Operating Conditions

The device is not guaranteed to operate beyond the Maximum Recommended Operating Conditions.

| Parameter | Rating |
|--|------------------|
| Supply Voltage (V_{IN}) | 4.5V to 18V |
| Output Voltage Range | 0.8V to V_{IN} |
| Ambient Temperature (T_A) | -40°C to +85°C |
| Package Thermal Resistance Exposed Pad SO-8 (Θ_{JA}) ⁽²⁾ | 50°C/W |

Note:

2. The value of Θ_{JA} is measured with the device mounted on 1-in² FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$. The value in any given application depends on the user's specific board design.

Electrical Characteristics

$T_A = 25^\circ\text{C}$, $V_{IN} = V_{EN} = 12\text{V}$, $V_{OUT} = 3.3\text{V}$ unless otherwise specified.⁽³⁾

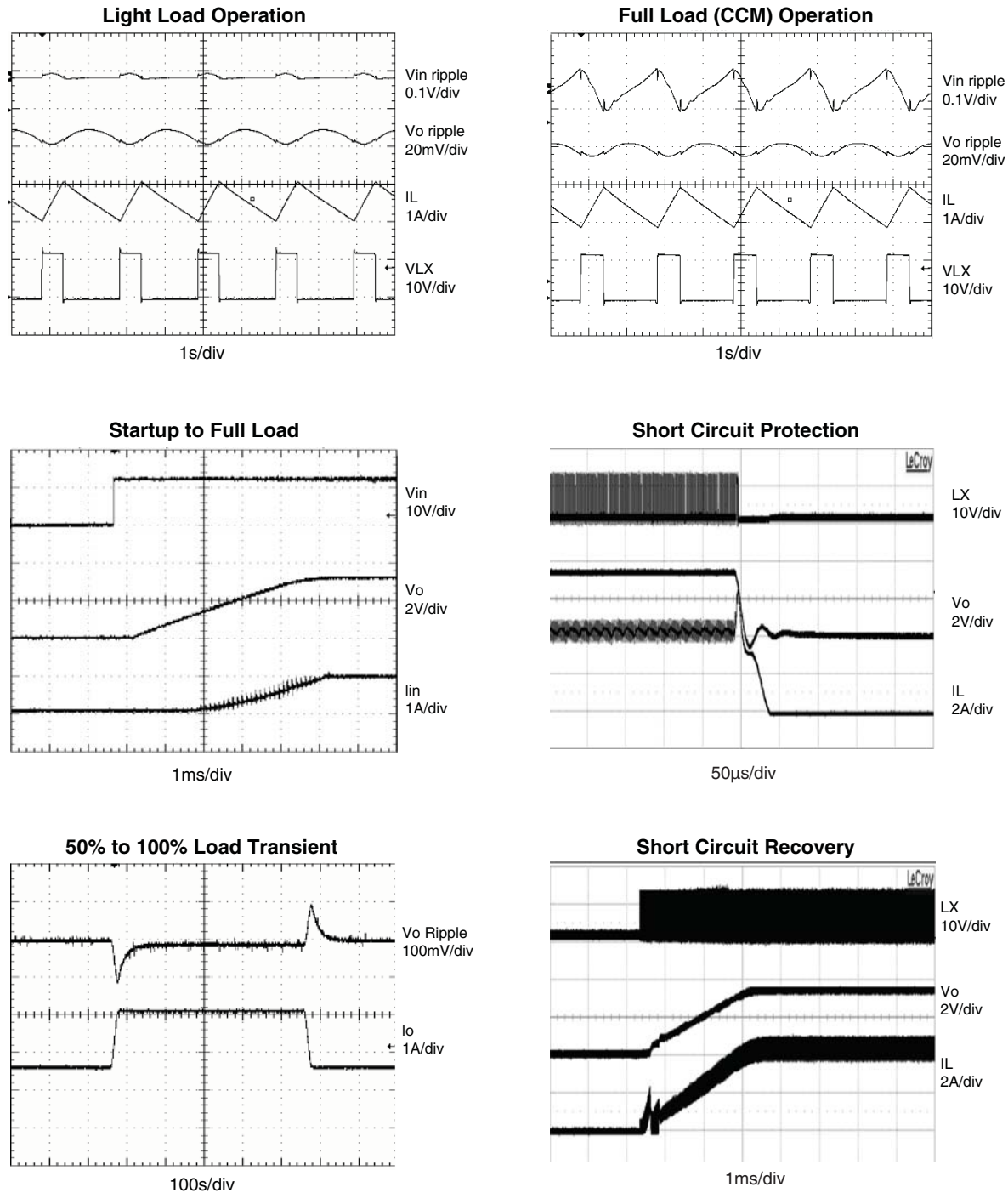
| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
|-------------------------|---------------------------------------|---|------------|--------------------------|------------|------------------|
| V_{IN} | Supply Voltage | | 4.5 | | 16 | V |
| V_{UVLO} | Input Under-Voltage Lockout Threshold | V_{IN} Rising V_{IN} Falling | | 4.1 3.7 | | V |
| I_{IN} | Supply Current (Quiescent) | $I_{OUT} = 0$, $V_{FB} = 1.2\text{V}$, $V_{EN} > 1.2\text{V}$ | | 1.6 | 2.5 | mA |
| I_{OFF} | Shutdown Supply Current | $V_{EN} = 0\text{V}$ | | 3 | 20 | μA |
| V_{FB} | Feedback Voltage | $T_A = 25^\circ\text{C}$ | 0.788 | 0.8 | 0.812 | V |
| | Load Regulation | | | 0.5 | | % |
| | Line Regulation | | | 1 | | % |
| I_{FB} | Feedback Voltage Input Current | | | | 200 | nA |
| ENABLE | | | | | | |
| V_{EN} | EN Input Threshold | Off Threshold On Threshold | 2 | | 0.6 | V |
| V_{HYS} | EN Input Hysteresis | | | 100 | | mV |
| MODULATOR | | | | | | |
| f_O | Frequency | | 350 | 500 | 600 | kHz |
| D_{MAX} | Maximum Duty Cycle | | 100 | | | % |
| D_{MIN} | Minimum Duty Cycle | | | | 6 | % |
| G_{VEA} | Error Amplifier Voltage Gain | | | 500 | | V/V |
| G_{EA} | Error Amplifier Transconductance | | | 200 | | $\mu\text{A/V}$ |
| PROTECTION | | | | | | |
| I_{LIM} | Current Limit | | 4.0 | | 5.0 | A |
| | Over-Temperature Shutdown Limit | T_J Rising T_J Falling | | 150 100 | | $^\circ\text{C}$ |
| t_{SS} | Soft Start Interval | | 3 | 5 | 7 | ms |
| POWER GOOD | | | | | | |
| V_{OLPG} | PGOOD LOW Voltage | $I_{OL} = 1\text{mA}$ | | | 0.5 | V |
| | PGOOD Leakage | | | | 1 | μA |
| V_{PGL} | PGOOD Threshold Voltage | | 87 | 90 | 92 | % V_O |
| | PGOOD Threshold Voltage Hysteresis | | | 3 | | % |
| t_{PG} | PGOOD Delay Time | | | 128 | | μs |
| PWM OUTPUT STAGE | | | | | | |
| | High-Side Switch On-Resistance | $V_{IN} = 12\text{V}$ $V_{IN} = 5\text{V}$ | | 97 166 | 130 200 | $\text{m}\Omega$ |
| | Low-Side Switch On-Resistance | $V_{IN} = 12\text{V}$ $V_{IN} = 5\text{V}$ | | 18 30 | 23 36 | $\text{m}\Omega$ |

Note:

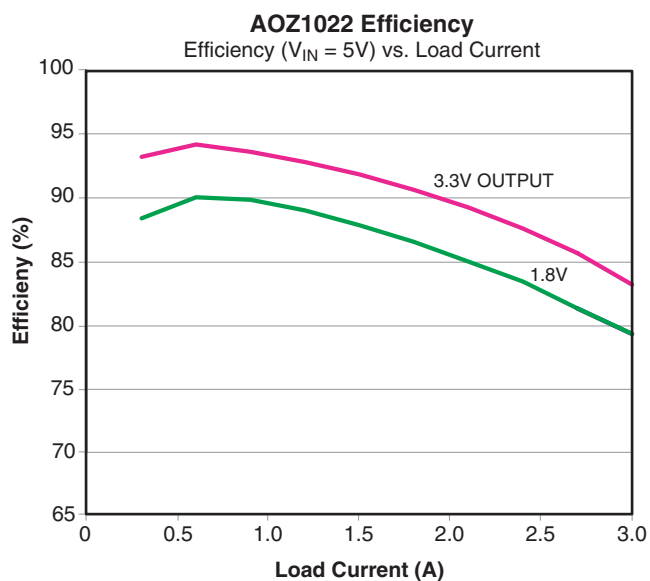
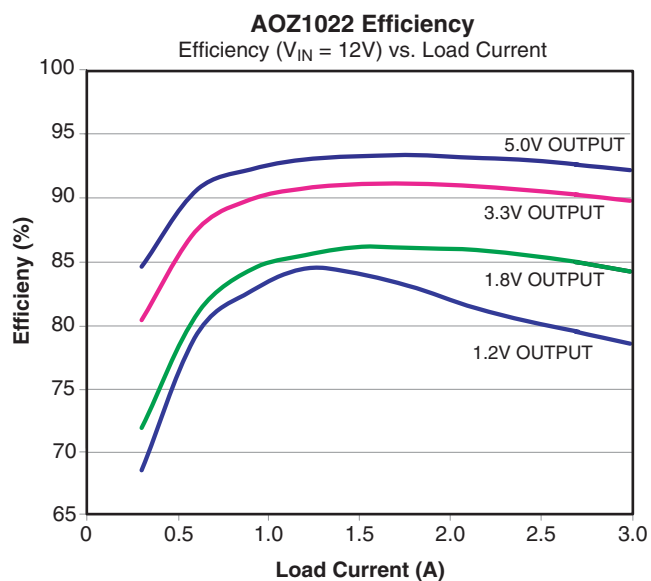
3. Specifications in **BOLD** indicate an ambient temperature range of -40°C to $+85^\circ\text{C}$. These specifications are guaranteed by design.

Typical Performance Characteristics

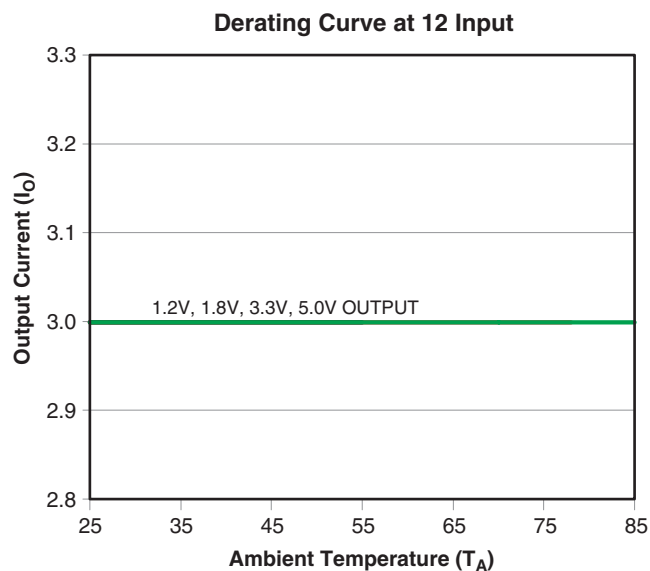
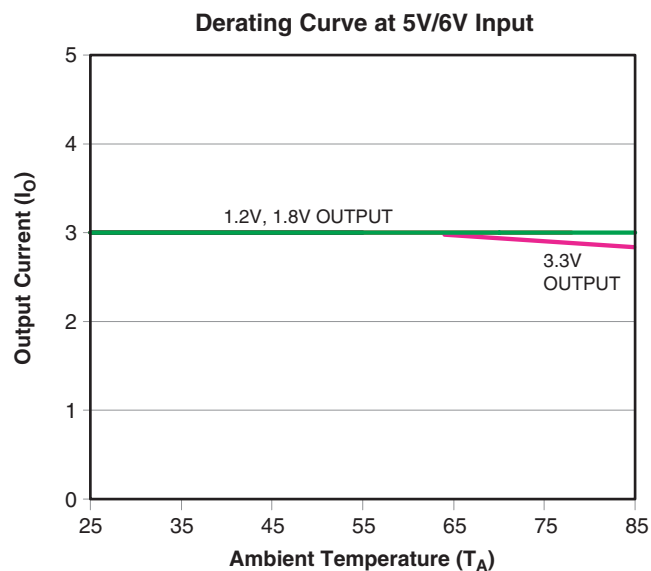
Circuit of Figure 1. $T_A = 25^\circ\text{C}$, $V_{IN} = V_{EN} = 12\text{V}$, $V_{OUT} = 3.3\text{V}$ unless otherwise specified.



Efficiency



Thermal Derating Curves



Detailed Description

The AOZ1022 is a current-mode step down regulator with integrated high-side PMOS switch and a low-side NMOS switch. It operates from a 4.5V to 16V input voltage range and supplies up to 3A of load current. The duty cycle can be adjusted from 6% to 100% allowing a wide range of output voltage. Features include enable control, Power-On Reset, input under voltage lockout, output over voltage protection, active high power good state, fixed internal soft-start and thermal shut down.

Enable and Soft Start

The AOZ1022 has an internal soft start feature to limit in-rush current and ensure the output voltage ramps up smoothly to regulation voltage. A soft start process begins when the input voltage rises to 4.1V and voltage on EN pin is HIGH. In the soft start process, the output voltage is typically ramped to regulation voltage in 4ms. The 4ms soft start time is set internally.

The EN pin of the AOZ1022 is active HIGH. Connect the EN pin to V_{IN} if the enable function is not used. Pulling EN to ground will disable the AOZ1022. Do not leave it open. The voltage on the EN pin must be above 2V to enable the AOZ1022. When voltage on the EN pin falls below 0.6V, the AOZ1022 is disabled. If an application circuit requires the AOZ1022 to be disabled, an open drain or open collector circuit should be used to interface to the EN pin.

Power Good

The output of Power-Good is an open drain N-channel MOSFET which supplies an active high power good stage. A pull-up resistor (R_3) should connect this pin to a DC power rail with maximum voltage of 6V. The AOZ1022 monitors the FB voltage. When FB voltage is lower than 90% of the normal voltage, N-channel MOSFET turns on and the Power-Good pin is pulled low. This indicates the power is abnormal.

Steady-State Operation

Under steady-state conditions, the converter operates in fixed frequency and Continuous-Conduction Mode (CCM).

The AOZ1022 integrates an internal P-MOSFET as the high-side switch. Inductor current is sensed by amplifying the voltage drop across the drain to source of the high side power MOSFET. Output voltage is divided down by the external voltage divider at the FB pin. The difference of the FB pin voltage and reference is amplified by the internal transconductance error amplifier. The error voltage, which shows on the COMP pin, is compared

against the current signal, which is sum of inductor current signal and ramp compensation signal, at the PWM comparator input. If the current signal is less than the error voltage, the internal high-side switch is on. The inductor current flows from the input through the inductor to the output. When the current signal exceeds the error voltage, the high-side switch is off. The inductor current is freewheeling through the internal low-side N-MOSFET switch to output. The internal adaptive FET driver guarantees no turn on overlap of both high-side and low-side switch.

Comparing with regulators using freewheeling Schottky diodes, the AOZ1022 uses freewheeling NMOSFET to realize synchronous rectification. It greatly improves the converter efficiency and reduces power loss in the low-side switch.

The AOZ1022 uses a P-Channel MOSFET as the high-side switch. It saves the bootstrap capacitor normally seen in a circuit which is using an NMOS switch. It allows 100% turn-on of the high-side switch to achieve linear regulation mode of operation. The minimum voltage drop from V_{IN} to V_O is the load current x DC resistance of MOSFET + DC resistance of buck inductor. It can be calculated by the equation below:

$$V_{O_MAX} = V_{IN} - I_O \times R_{DS(ON)}$$

where;

V_{O_MAX} is the maximum output voltage,

V_{IN} is the input voltage from 4.5V to 16V,

I_O is the output current from 0A to 3A, and

$R_{DS(ON)}$ is the on resistance of internal MOSFET, the value is between 97m Ω and 200m Ω depending on input voltage and junction temperature.

Switching Frequency

The AOZ1022 switching frequency is fixed and set by an internal oscillator. The practical switching frequency could range from 350kHz to 600kHz due to device variation.

Output Voltage Programming

Output voltage can be set by feeding back the output to the FB pin by using a resistor divider network. See the application circuit shown in Figure 1. The resistor divider network includes R_1 and R_2 . Usually, a design is started by picking a fixed R_2 value and calculating the required R_1 with equation on the next page:

$$V_O = 0.8 \times \left(1 + \frac{R_1}{R_2} \right)$$

Some standard value of R_1 , R_2 and most used output voltage values are listed in Table 1.

| V_O (V) | R_1 (k Ω) | R_2 (k Ω) |
|-----------|---------------------|---------------------|
| 0.8 | 1.0 | open |
| 1.2 | 4.99 | 10 |
| 1.5 | 10 | 11.5 |
| 1.8 | 12.7 | 10.2 |
| 2.5 | 21.5 | 10 |
| 3.3 | 31.1 | 10 |
| 5.0 | 52.3 | 10 |

The combination of R_1 and R_2 should be large enough to avoid drawing excessive current from the output, which will cause power loss.

Since the switch duty cycle can be as high as 100%, the maximum output voltage can be set as high as the input voltage minus the voltage drop on upper PMOS and inductor.

Protection Features

The AOZ1022 has multiple protection features to prevent system circuit damage under abnormal conditions.

Over Current Protection (OCP)

The sensed inductor current signal is also used for over current protection. Since the AOZ1022 employs peak current mode control, the COMP pin voltage is proportional to the peak inductor current. The COMP pin voltage is limited to be between 0.4V and 2.5V internally. The peak inductor current is automatically limited cycle by cycle.

When the output is shorted to ground under fault conditions, the inductor current decays very slow during a switching cycle because of $V_O = 0V$. To prevent catastrophic failure, a secondary current limit is designed inside the AOZ1022. The measured inductor current is compared against a preset voltage which represents the current limit, between 3.5A and 5.0A. When the output current is more than current limit, the high side switch will be turned off. The converter will initiate a soft start once the over-current condition is resolved.

Power-On Reset (POR)

A power-on reset circuit monitors the input voltage. When the input voltage exceeds 4.1V, the converter starts operation. When input voltage falls below 3.7V, the converter shuts down.

Thermal Protection

An internal temperature sensor monitors the junction temperature. It shuts down the internal control circuit and high side PMOS if the junction temperature exceeds 150°C. The regulator will restart automatically under the control of soft-start circuit when the junction temperature decreases to 100°C.

Application Information

The basic AOZ1022 application circuit is show in Figure 1. Component selection is explained below.

Input Capacitor

The input capacitor must be connected to the V_{IN} pin and PGND pin of AOZ1022 to maintain steady input voltage and filter out the pulsing input current. The voltage rating of input capacitor must be greater than maximum input voltage plus ripple voltage.

The input ripple voltage can be approximated by equation below:

$$\Delta V_{IN} = \frac{I_O}{f \times C_{IN}} \times \left(1 - \frac{V_O}{V_{IN}}\right) \times \frac{V_O}{V_{IN}}$$

Since the input current is discontinuous in a buck converter, the current stress on the input capacitor is another concern when selecting the capacitor. For a buck circuit, the RMS value of input capacitor current can be calculated by:

$$I_{CIN_RMS} = I_O \times \sqrt{\frac{V_O}{V_{IN}} \left(1 - \frac{V_O}{V_{IN}}\right)}$$

if we let m equal the conversion ratio:

$$\frac{V_O}{V_{IN}} = m$$

The relation between the input capacitor RMS current and voltage conversion ratio is calculated and shown in Figure 2 on the next page. It can be seen that when V_O is half of V_{IN} , C_{IN} is under the worst current stress. The worst current stress on C_{IN} is $0.5 \times I_O$.

For reliable operation and best performance, the input capacitors must have current rating higher than I_{CIN_RMS} at worst operating conditions. Ceramic capacitors are preferred for input capacitors because of their low ESR and high current rating. Depending on the application circuits, other low ESR tantalum capacitor may also be used. When selecting ceramic capacitors, X5R or X7R type dielectric ceramic capacitors should be used for their better temperature and voltage characteristics.

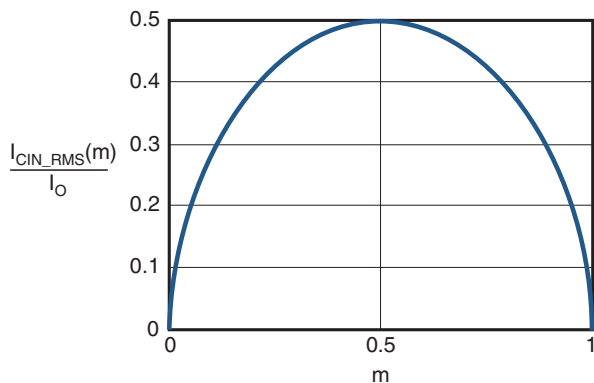


Figure 2. I_{CIN} vs. Voltage Conversion Ratio

Note that the ripple current rating from capacitor manufacturers are based on certain amount of life time. Further de-rating may be necessary in practical design.

Inductor

The inductor is used to supply constant current to output when it is driven by a switching voltage. For given input and output voltage, inductance and switching frequency together decide the inductor ripple current, which is:

$$\Delta I_L = \frac{V_O}{f \times L} \times \left(1 - \frac{V_O}{V_{IN}}\right)$$

The peak inductor current is:

$$I_{Lpeak} = I_O + \frac{\Delta I_L}{2}$$

High inductance gives low inductor ripple current but requires larger size inductor to avoid saturation. Low ripple current reduces inductor core losses. It also reduces RMS current through inductor and switches, which results in less conduction loss. Usually, peak to peak ripple current on inductor is designed to be 20% to 30% of output current.

When selecting the inductor, make sure it is able to handle the peak current without saturation even at the highest operating temperature.

The inductor takes the highest current in a buck circuit. The conduction loss on inductor need to be checked for thermal and efficiency requirements.

Surface mount inductors in different shape and styles are available from Coilcraft, Elytone and Murata. Shielded inductors are small and radiate less EMI noise. But they cost more than unshielded inductors. The choice depends on EMI requirement, price and size.

Output Capacitor

The output capacitor is selected based on the DC output voltage rating, output ripple voltage specification and ripple current rating.

The selected output capacitor must have a higher rated voltage specification than the maximum desired output voltage including ripple. De-rating needs to be considered for long term reliability.

Output ripple voltage specification is another important factor for selecting the output capacitor. In a buck converter circuit, output ripple voltage is determined by inductor value, switching frequency, output capacitor value and ESR. It can be calculated by the equation below:

$$\Delta V_O = \Delta I_L \times \left(ESR_{CO} + \frac{1}{8 \times f \times C_O}\right)$$

where,

C_O is output capacitor value, and

ESR_{CO} is the equivalent series resistance of the output capacitor.

When low ESR ceramic capacitor is used as output capacitor, the impedance of the capacitor at the switching frequency dominates. Output ripple is mainly caused by capacitor value and inductor ripple current. The output ripple voltage calculation can be simplified to:

$$\Delta V_O = \Delta I_L \times \left(\frac{1}{8 \times f \times C_O}\right)$$

If the impedance of ESR at switching frequency dominates, the output ripple voltage is mainly decided by capacitor ESR and inductor ripple current. The output ripple voltage calculation can be further simplified to:

$$\Delta V_O = \Delta I_L \times ESR_{CO}$$

For lower output ripple voltage across the entire operating temperature range, X5R or X7R dielectric type of ceramic, or other low ESR tantalum are recommended to be used as output capacitors.

In a buck converter, output capacitor current is continuous. The RMS current of output capacitor is decided by the peak to peak inductor ripple current. It can be calculated by:

$$I_{CO_RMS} = \frac{\Delta I_L}{\sqrt{12}}$$

Usually, the ripple current rating of the output capacitor is a smaller issue because of the low current stress. When the buck inductor is selected to be very small and induc-

tor ripple current is high, the output capacitor could be overstressed.

Loop Compensation

The AOZ1022 employs peak current mode control for easy use and fast transient response. Peak current mode control eliminates the double pole effect of the output L&C filter. It greatly simplifies the compensation loop design.

With peak current mode control, the buck power stage can be simplified to be a one-pole and one-zero system in frequency domain. The pole is the dominant pole can be calculated by:

$$f_{p1} = \frac{1}{2\pi \times C_O \times R_L}$$

The zero is an ESR zero due to output capacitor and its ESR. It is can be calculated by:

$$f_{z1} = \frac{1}{2\pi \times C_O \times ESR_{CO}}$$

where;

C_O is the output filter capacitor,

R_L is load resistor value, and

ESR_{CO} is the equivalent series resistance of output capacitor.

The compensation design is actually to shape the converter control loop transfer function to get the desired gain and phase. Several different types of compensation network can be used for the AOZ1022. In most cases, a series capacitor and resistor network connected to the COMP pin sets the pole-zero and is adequate for a stable high-bandwidth control loop.

In the AOZ1022, FB pin and COMP pin are the inverting input and the output of internal error amplifier. A series R and C compensation network connected to COMP provides one pole and one zero. The pole is:

$$f_{p2} = \frac{G_{EA}}{2\pi \times C_C \times G_{VEA}}$$

where;

G_{EA} is the error amplifier transconductance, which is 200×10^{-6} A/V,

G_{VEA} is the error amplifier voltage; and

C_2 is compensation capacitor in Figure 1.

The zero given by the external compensation network, capacitor C_2 and resistor R_3 , is located at:

$$f_{z2} = \frac{1}{2\pi \times C_C \times R_C}$$

To design the compensation circuit, a target crossover frequency f_C for close loop must be selected. The system crossover frequency is where control loop has unity gain. The crossover is the also called the converter bandwidth. Generally a higher bandwidth means faster response to load transient. However, the bandwidth should not be too high because of system stability concern. When designing the compensation loop, converter stability under all line and load condition must be considered.

Usually, it is recommended to set the bandwidth to be equal or less than 1/10 of switching frequency. The AOZ1022 operates at a frequency range from 350kHz to 600kHz. It is recommended to choose a crossover frequency equal or less than 40kHz.

$$f_C = 40kHz$$

The strategy for choosing R_C and C_C is to set the cross over frequency with R_C and set the compensator zero with C_C . Using selected crossover frequency, f_C , to calculate R_3 :

$$R_C = f_C \times \frac{V_O}{V_{FB}} \times \frac{2\pi \times C_2}{G_{EA} \times G_{CS}}$$

where;

where f_C is desired crossover frequency. For best performance, f_C is set to be about 1/10 of switching frequency,

V_{FB} is 0.8V,

G_{EA} is the error amplifier transconductance, which is 200×10^{-6} A/V, and

G_{CS} is the current sense circuit transconductance, which is 6.86 A/V

The compensation capacitor C_C and resistor R_C together make a zero. This zero is put somewhere close to the dominate pole f_{p1} but lower than 1/5 of selected crossover frequency. C_2 can be selected by:

$$C_C = \frac{1.5}{2\pi \times R_C \times f_{p1}}$$

The above equation can be simplified to:

$$C_C = \frac{C_O \times R_L}{R_C}$$

An easy-to-use application software which helps to design and simulate the compensation loop can be found at www.aosmd.com.

Thermal Management and Layout Consideration

In the AOZ1022 buck regulator circuit, high pulsing current flows through two circuit loops. The first loop starts from the input capacitors, to the V_{IN} pin, to the LX pins, to the filter inductor, to the output capacitor and load, and then return to the input capacitor through ground. Current flows in the first loop when the high side switch is on. The second loop starts from inductor, to the output capacitors and load, to the anode of Schottky diode, to the cathode of Schottky diode. Current flows in the second loop when the low side diode is on.

In PCB layout, minimizing the two loops area reduces the noise of this circuit and improves efficiency. A ground plane is strongly recommended to connect input capacitor, output capacitor, and PGND pin of the AOZ1022.

In the AOZ1022 buck regulator circuit, the major power dissipating components are the AOZ1022 and the output inductor. The total power dissipation of converter circuit can be measured by input power minus output power.

$$P_{total_loss} = V_{IN} \times I_{IN} - V_O \times I_O$$

The power dissipation of inductor can be approximately calculated by output current and DCR of inductor.

$$P_{inductor_loss} = I_O^2 \times R_{inductor} \times 1.1$$

The actual junction temperature can be calculated with power dissipation in the AOZ1022 and thermal impedance from junction to ambient.

$$T_{junction} = (P_{total_loss} - P_{inductor_loss}) \times \Theta_{JA}$$

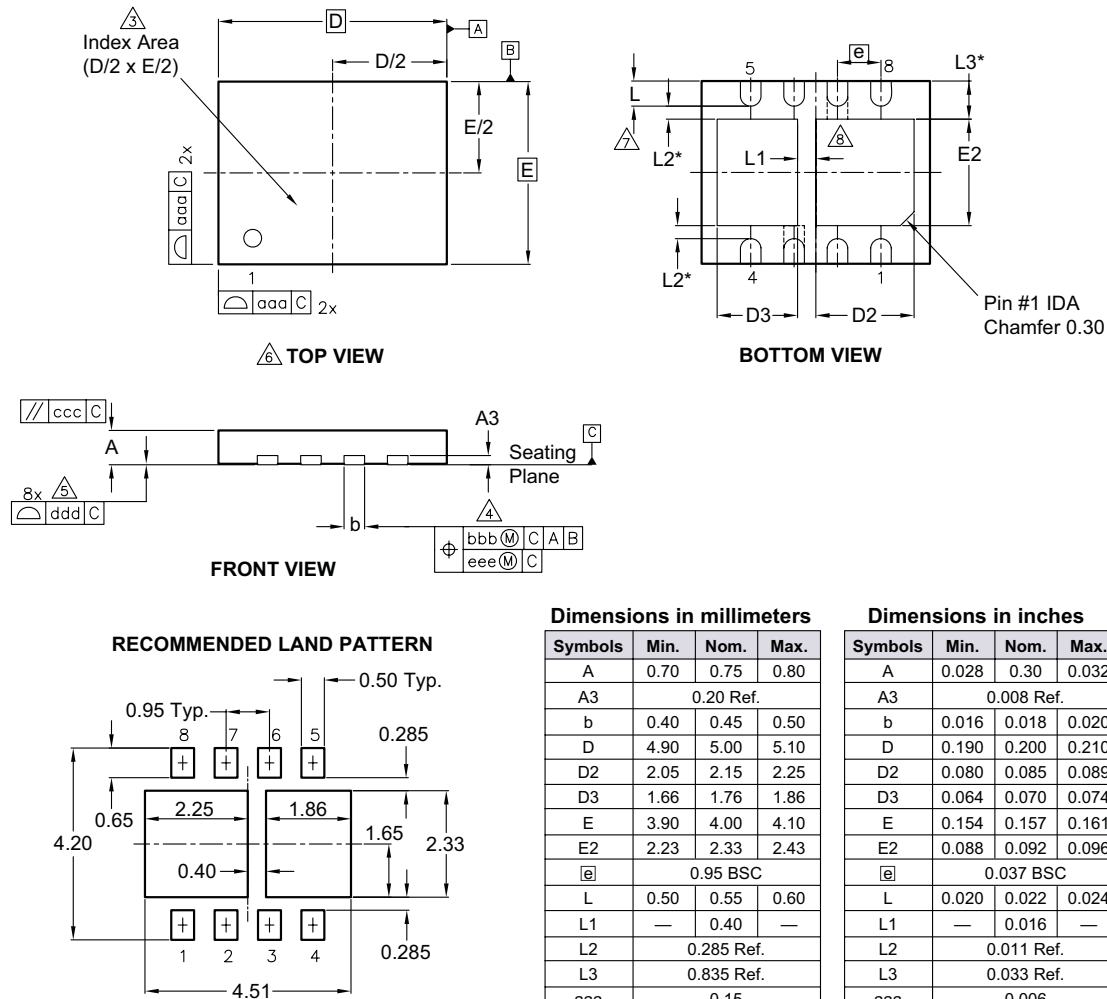
The maximum junction temperature of AOZ1022 is 150°C, which limits the maximum load current capability. Please see the thermal de-rating curves for maximum load current of the AOZ1022 under different ambient temperature.

The thermal performance of the AOZ1022 is strongly affected by the PCB layout. Extra care should be taken by users during design process to ensure that the IC will operate under the recommended environmental conditions.

The AOZ1022 comes in an EPAD SO-8 package. Layout tips are listed below for the best electric and thermal performance. Figure 3 illustrates a PCB layout example of the AOZ1022.

1. The LX pins are connected to internal PFET and NFET drains. They are low resistance thermal conduction path and the most noisy switching node. Connected a large copper plane to the LX pin to help thermal dissipation.
2. Do not use thermal relief connection to the V_{IN} and the PGND pin. Pour a maximized copper area to the PGND pin and the V_{IN} pin to help thermal dissipation.
3. Input capacitor should be connected to the V_{IN} pin and the PGND pin as close as possible.
4. A ground plane is preferred. If a ground plane is not used, separate PGND from AGND and connect them only at one point to avoid the PGND pin noise coupling to the AGND pin.
5. Make the current trace from LX pins to L to Co to the PGND as short as possible.
6. Pour copper plane on all unused board area and connect it to stable DC nodes, like V_{IN} , GND or V_{OUT} .
7. Keep sensitive signal trace far away from the LX pins.

Package Dimensions, DFN 5x4



Dimensions in millimeters

| Symbols | Min. | Nom. | Max. |
|---------|------------|------|------|
| A | 0.70 | 0.75 | 0.80 |
| A3 | 0.20 Ref. | | |
| b | 0.40 | 0.45 | 0.50 |
| D | 4.90 | 5.00 | 5.10 |
| D2 | 2.05 | 2.15 | 2.25 |
| D3 | 1.66 | 1.76 | 1.86 |
| E | 3.90 | 4.00 | 4.10 |
| E2 | 2.23 | 2.33 | 2.43 |
| ⓐ | 0.95 BSC | | |
| L | 0.50 | 0.55 | 0.60 |
| L1 | — | 0.40 | — |
| L2 | 0.285 Ref. | | |
| L3 | 0.835 Ref. | | |
| aaa | 0.15 | | |
| bbb | 0.10 | | |
| ccc | 0.10 | | |
| ddd | 0.08 | | |
| eee | 0.05 | | |

Dimensions in inches

| Symbols | Min. | Nom. | Max. |
|---------|------------|-------|-------|
| A | 0.028 | 0.30 | 0.032 |
| A3 | 0.008 Ref. | | |
| b | 0.016 | 0.018 | 0.020 |
| D | 0.190 | 0.200 | 0.210 |
| D2 | 0.080 | 0.085 | 0.089 |
| D3 | 0.064 | 0.070 | 0.074 |
| E | 0.154 | 0.157 | 0.161 |
| E2 | 0.088 | 0.092 | 0.096 |
| ⓐ | 0.037 BSC | | |
| L | 0.020 | 0.022 | 0.024 |
| L1 | — | 0.016 | — |
| L2 | 0.011 Ref. | | |
| L3 | 0.033 Ref. | | |
| aaa | 0.006 | | |
| bbb | 0.004 | | |
| ccc | 0.004 | | |
| ddd | 0.003 | | |
| eee | 0.002 | | |

Notes:

1. Dimensions and tolerancing conform to ASME Y14.5M-1994.

2. All dimensions are in millimeters.

③ The location of the terminal #1 identifier and terminal numbering convention conforms to JEDEC publication 95 SP-002.

④ Dimension b applies to metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip. If the terminal has the optional radius on the other end of the terminal, the dimension b should not be measured in that radius area.

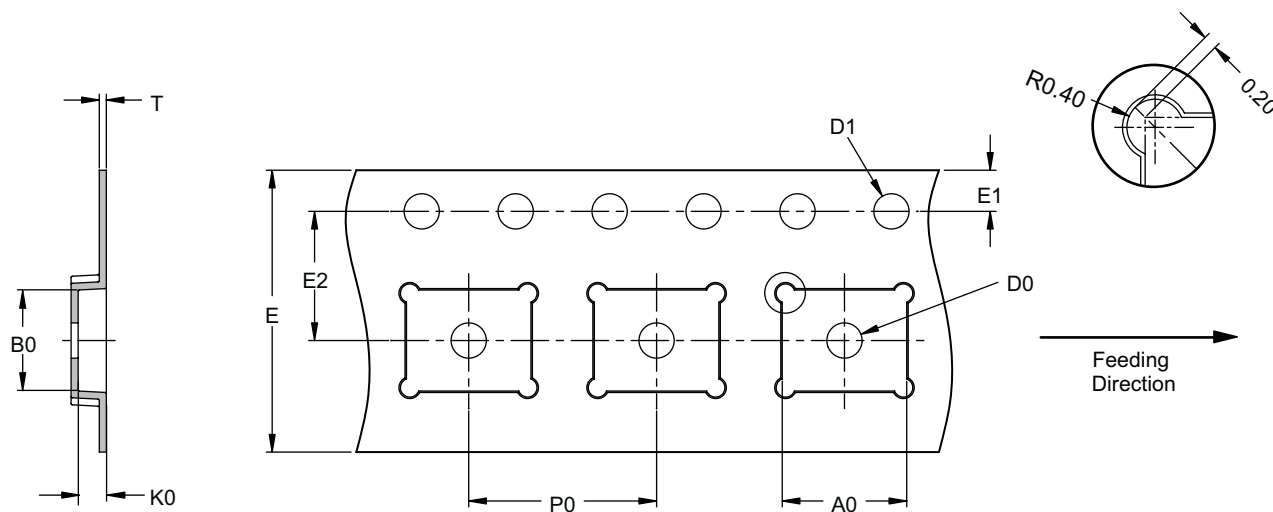
⑤ Coplanarity applies to the terminals and all other bottom surface metallization.

⑥ Drawing shown are for illustration only.

⑦ The dimensions with * are just for reference

⑧ Pin #3 and Pin #7 are fused to DAP.

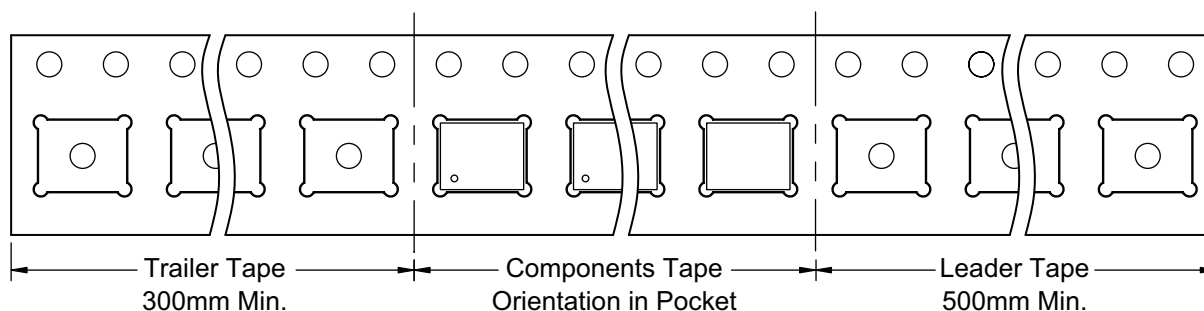
Tape Dimensions, DFN 5x4



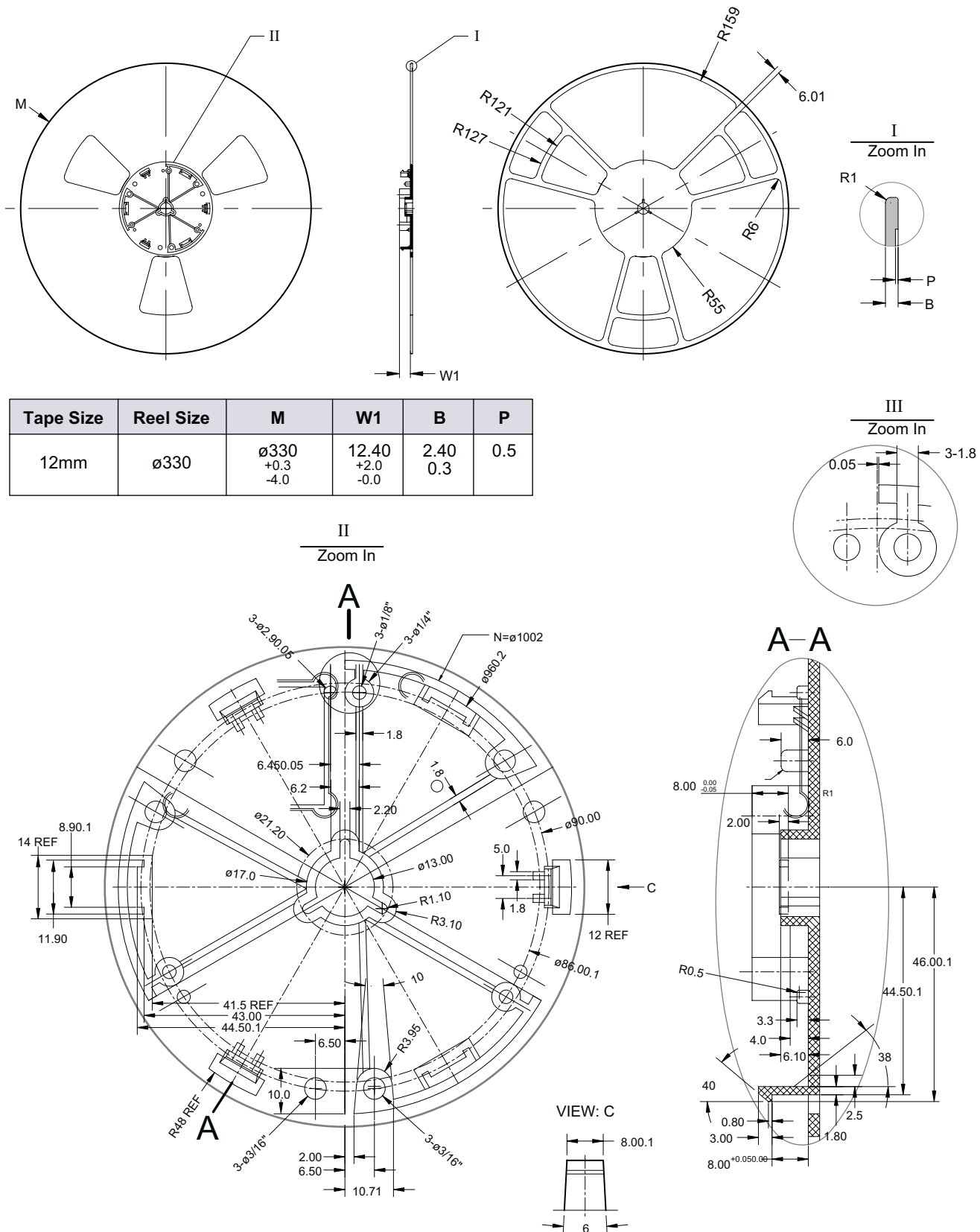
UNIT: mm

| Package | A0 | B0 | K0 | D0 | D1 | E | E1 | E2 | P0 | P1 | P2 | T |
|--------------------|---------------|---------------|---------------|--------------|--------------------|----------------|---------------|---------------|---------------|---------------|---------------|---------------|
| DFN 5x4 (12 mm) | 5.30 ±0.10 | 4.30 ±0.10 | 1.20 ±0.10 | 1.50 Min. | 1.50 +0.10 / -0 | 12.00 ±0.30 | 1.75 ±0.10 | 5.50 ±0.10 | 8.00 ±0.10 | 4.00 ±0.20 | 2.00 ±0.10 | 0.30 ±0.05 |

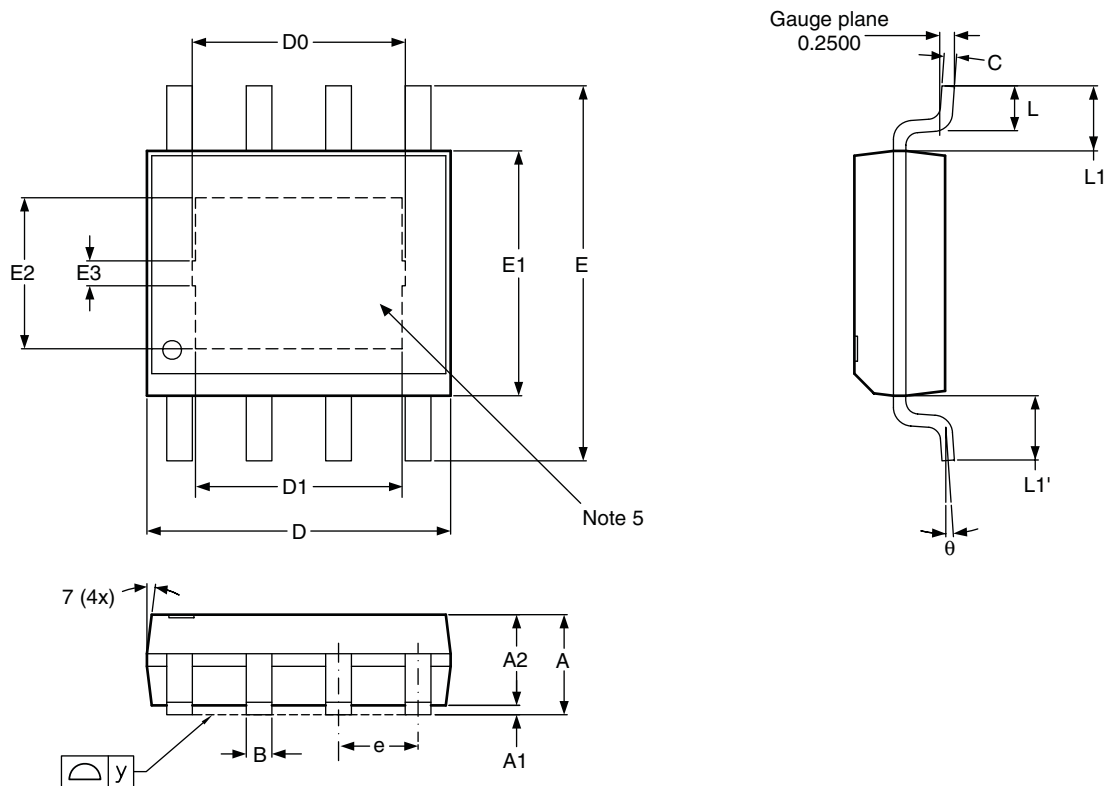
Leader/Trailer and Orientation



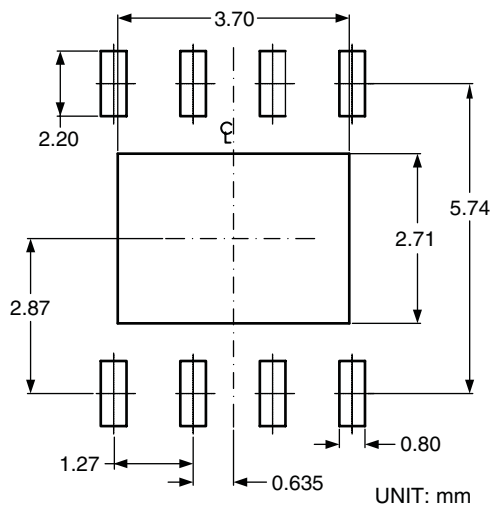
Reel Dimensions, DFN 5x4



Package Dimensions, EPAD SO-8



RECOMMENDED LAND PATTERN



Dimensions in millimeters

| Symbols | Min. | Nom. | Max. |
|---------|----------|-------|------|
| A | 1.40 | 1.55 | 1.70 |
| A1 | 0.00 | 0.05 | 0.10 |
| A2 | 1.40 | 1.50 | 1.60 |
| B | 0.31 | 0.406 | 0.51 |
| C | 0.17 | — | 0.25 |
| D | 4.80 | 4.96 | 5.00 |
| D0 | 3.20 | 3.40 | 3.60 |
| D1 | 3.10 | 3.30 | 3.50 |
| E | 5.80 | 6.00 | 6.20 |
| e | — | 1.27 | — |
| E1 | 3.80 | 3.90 | 4.00 |
| E2 | 2.21 | 2.41 | 2.61 |
| E3 | 0.40 REF | | |
| L | 0.40 | 0.95 | 1.27 |
| y | — | — | 0.10 |
| θ | 0 | 3 | 8 |
| L1-L1' | — | 0.04 | 0.12 |
| L1 | 1.04 REF | | |

Dimensions in inches

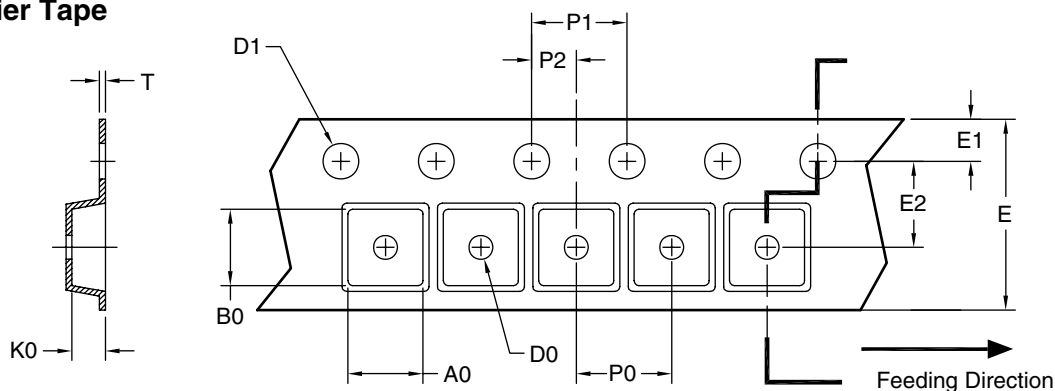
| Symbols | Min. | Nom. | Max. |
|---------|-----------|-------|-------|
| A | 0.055 | 0.061 | 0.067 |
| A1 | 0.000 | 0.002 | 0.004 |
| A2 | 0.055 | 0.059 | 0.063 |
| B | 0.012 | 0.016 | 0.020 |
| C | 0.007 | — | 0.010 |
| D | 0.189 | 0.195 | 0.197 |
| D0 | 0.126 | 0.134 | 0.142 |
| D1 | 0.122 | 0.130 | 0.138 |
| E | 0.228 | 0.236 | 0.244 |
| e | — | 0.050 | — |
| E1 | 0.150 | 0.153 | 0.157 |
| E2 | 0.087 | 0.095 | 0.103 |
| E3 | 0.016 REF | | |
| L | 0.016 | 0.037 | 0.050 |
| y | — | — | 0.004 |
| θ | 0 | 3 | 8 |
| L1-L1' | — | 0.002 | 0.005 |
| L1 | 0.041 REF | | |

Notes:

1. Package body sizes exclude mold flash and gate burrs.
2. Dimension L is measured in gauge plane.
3. Tolerance 0.10mm unless otherwise specified.
4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.
5. Die pad exposure size is according to lead frame design.
6. Followed from JEDEC MS-012

Tape and Reel Dimensions, EPAD SO-8

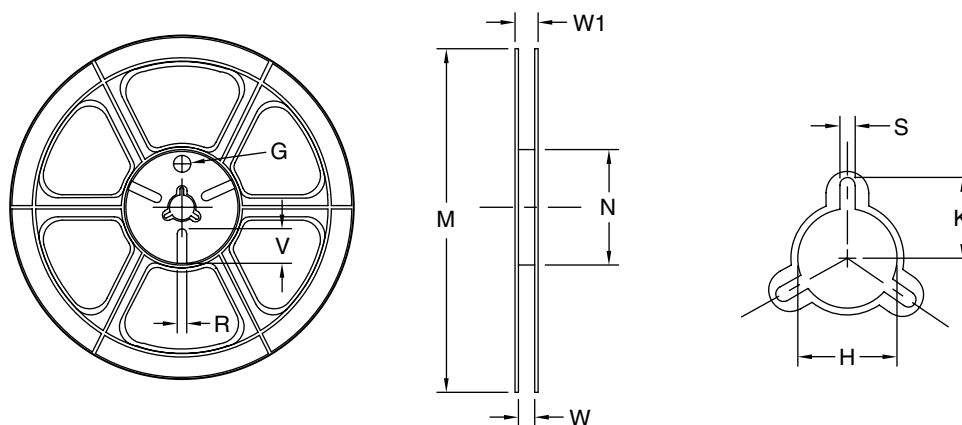
Carrier Tape



UNIT: mm

| Package | A0 | B0 | K0 | D0 | D1 | E | E1 | E2 | P0 | P1 | P2 | T |
|----------------|---------------|---------------|---------------|---------------|---------------|----------------|---------------|---------------|---------------|---------------|---------------|---------------|
| SO-8 (12mm) | 6.40 ±0.10 | 5.20 ±0.10 | 2.10 ±0.10 | 1.60 ±0.10 | 1.50 ±0.10 | 12.00 ±0.10 | 1.75 ±0.10 | 5.50 ±0.10 | 8.00 ±0.10 | 4.00 ±0.10 | 2.00 ±0.10 | 0.25 ±0.10 |

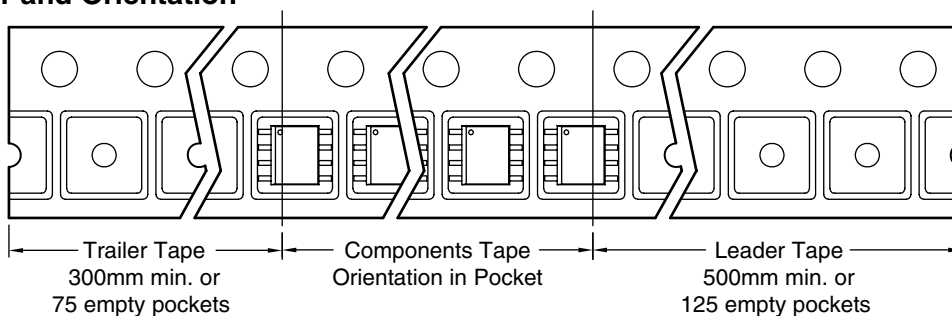
Reel



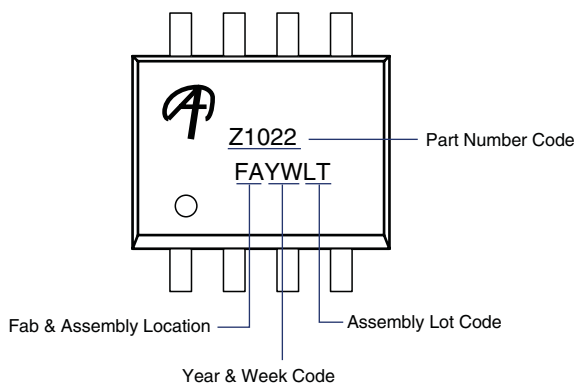
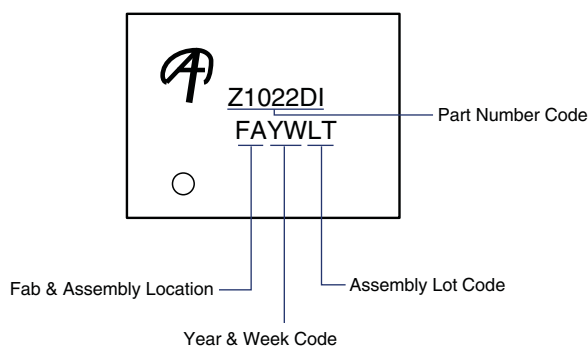
UNIT: mm

| Tape Size | Reel Size | M | N | W | W1 | H | K | S | G | R | V |
|-----------|-----------|------------------|-----------------|----------------|----------------|-----------------------|-------|---------------|---|---|---|
| 12mm | ø330 | ø330.00 ±0.50 | ø97.00 ±0.10 | 13.00 ±0.30 | 17.40 ±1.00 | ø13.00 +0.50/-0.20 | 10.60 | 2.00 ±0.50 | — | — | — |

Leader/Trailer and Orientation



Part Marking



This data sheet contains preliminary data; supplementary data may be published at a later date. Alpha & Omega Semiconductor reserves the right to make changes at any time without notice.

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2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.